# Radiation-hard optical link for SLHC

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**Abstract**. We study the feasibility of fabricating an optical link for the SLHC ATLAS silicon tracker based on the current pixel optical link architecture. The electrical signals between the current pixel modules and the optical modules are transmitted via micro-twisted cables. The optical signals between the optical modules and the data acquisition system are transmitted via rad-hard SIMM fibres spliced to rad-tolerant GRIN fibres. The link has several nice features. We have measured the bandwidths of the micro twisted-pair cables to be  $\sim 1$  Gb/s and the fusion spliced fibre ribbon to be  $\sim 2$  Gb/s. We have irradiated PIN and VCSEL arrays with 24 GeV protons and find the arrays survive to the SLHC dosage. We have also demonstrated the feasibility of fabricating a novel opto-pack for housing VCSEL and PIN arrays with BeO as the substrate.

#### 1. Introduction

The SLHC is designed to increase the luminosity of the LHC by a factor of ten to  $10^{35}$  cm<sup>-2</sup>s<sup>-1</sup>. Accordingly, the radiation level at the detector is expected to increase by a similar factor. The increased data rate and radiation level will pose new challenges for a tracker situated close to the interaction region. The present optical link [1] of the ATLAS pixel detector [2] is mounted on a patch panel instead of directly on a pixel module. This separation greatly reduces the radiation level at the optical modules (opto-boards) and simplifies the design and production of both the pixel modules and opto-boards. Data communication between the separated modules is achieved by transmitting electrical signals using ~ 1 m of micro twisted-pair cables. The optical signals between each opto-board and the off-detector optical electronics are then transmitted via 8 m of rad-hard/low bandwidth SIMM fibre ribbon fusion spliced to 70 m of rad-tolerant/medium bandwidth GRIN fibre ribbon. The optical signals are generated and received using the VCSEL and PIN arrays, respectively. We currently transmit optical signals at 80 Mb/s and expect to transmit signals at ~ 1 Gb/s for the SLHC. If the present architecture can transmit signals at the higher speed, the constraint of requiring no extra service space is automatically satisfied.

We have started an R&D program to study the feasibility of an upgrade based on the optical link architecture of the current pixel detector while taking advantage of the several years of R&D effort and production experience. In this paper, we present results on the bandwidth measurement of micro twisted-pair cables and fusion spliced SIMM/GRIN fibers and the radiation hardness of VCSEL and

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PIN arrays. In addition, we report the results on a novel opto-pack for housing VCSEL and PIN arrays fabricated with BeO as the substrate.

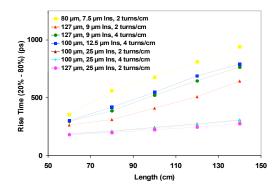
## 2. Bandwidth of micro twisted-pair cables

Commercial copper cables [3] can transmit several Gb/s over tens of meters. However, the diameters of these cables are too large for the pixel detector. The present pixel optical link uses a micro twisted-pair of wires for transmission of low voltage differential signals (LVDS) between a pixel module and the driver and receiver chips on an opto-board. Each pair of wires is twisted 5 turns per inch (TPI) which corresponds to 2 turns per cm. For barrel pixel detectors, each wire is aluminium with a diameter of 100  $\mu$ m (38 AWG) plus 25  $\mu$ m of insulation, for an outer diameter of 150  $\mu$ m. The length of the twisted pairs varies from 81 to 142 cm. The wires for the endcap pixel detector are finer, 60  $\mu$ m with 12  $\mu$ m of insulation. The length of these copper twisted pairs is ~80 cm. The impedance of the twisted pairs is ~75  $\Omega$ .

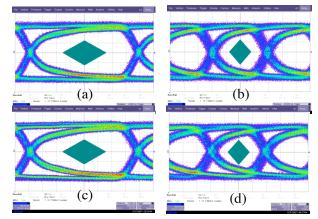
We have measured the bandwidths of micro twisted-pairs of various lengths, diameters, and numbers of turns per cm [4]. We transmitted LVDS pseudo-random data in the selected cable and measured the signal characteristics at the termination with a LeCroy WaveMASTER 8600A (6 GHz) oscilloscope and differential probe (7.5 GHz). The rise times of the cables are shown in figure 1. The thickest cable tested with 25  $\mu$ m of insulation and 2 turns/cm has the fastest rise time. However, the current barrel cable which is slightly thinner has similar performance.

The eye diagrams produced by transmitting pseudo-random data of 640 Mb/s and 1,280 Mb/s in the current barrel cable and the thicker cable are shown in figure 2. The masks shown are adapted from figure 39-5 and table 39-4 of the Gigabit Ethernet Specification (IEEE Standard 802.3) with the mask voltage levels modified to match the LVDS receiver chip used. From these figures, it is evident that the micro-twisted cables are adequate for transmitting signals at 640 Mb/s and that transmission at 1,280 Mb/s might be acceptable. The thicker cable has a slightly higher bandwidth with the slightly more open eye diagrams.

We have previously shown that a fusion spliced SIMM/GRIN fiber can adequately transmit signals up to 2 Gb/s and hence the transmission bandwidth of the wire link will be the limiting factor in the present pixel detector transmission lines [5].



**Figure 1:** The rise times (20-80%) of the micro twisted-pairs vs. wire length for wires of various diameters and turns per cm.



**Figure 2:** Eye diagrams for signals of (a) 640 and (b) 1,280 Mb/s for the 127  $\mu$ m cable of 1.4 m with 25  $\mu$ m of insulation and 2 turns/cm. (c,d) show the corresponding signals for the pixel barrel cable.

### 3. Radiation hardness of PIN and VCSEL arrays

We use the Non Ionizing Energy Loss (NIEL) scaling hypothesis to estimate the SLHC fluences [6-8] at the present pixel optical link location (PP0). The estimate is based on the assumption that the main

radiation effect is bulk damage in the VCSEL and PIN with the displacement of atoms. After five years of operation at the SLHC  $(3,000 \text{ fb}^{-1})$ , we expect the silicon component (PIN) to be exposed to a maximum total fluence of 1.5 x  $10^{15}$  1-MeV  $n_{eq}/cm^2$  [9]. The corresponding fluence for a GaAs component (VCSEL) is 8.2 x  $10^{15}$  1-MeV  $n_{eq}/cm^2$ . We study the response of the optical link to a high dose of 24 GeV protons. The expected equivalent fluences at LHC are 2.6 and 1.6 x  $10^{15}$  p/cm<sup>2</sup>, respectively. For simplicity, we present the results with dosage in Mrad, 69 and 34 Mrad, respectively.

We irradiated four opto-boards with PIN and VCSEL arrays from various vendors using 24 GeV protons at CERN. Each board was instrumented with one silicon PIN array and a pair of GaAs VCSEL arrays. The PIN arrays were all fabricated by one vendor, Truelight, and the VCSEL arrays were fabricated by three vendors, Optowell, Advanced Optical Components (AOC), and ULM Photonics (two varieties, 5 and 10 Gb/s). On the opto-boards, each of the PIN and VCSEL arrays coupled to radiation-hard ASICs produced for the current pixel optical link, the DORIC (Digital Opto Receiver Integrated Circuit) and VDC (VCSEL Driver Chip). Furthermore, the opto-boards were mounted on a shuttle system which enabled us to easily move in and out of the beam for annealing of the VCSEL arrays.

The test system monitored various parameters of the opto-boards throughout the irradiation. Of particular interest was the optical power of the VCSEL arrays vs. dosage as shown in figure 3. The power decreased during the irradiation as expected. We annealed the arrays by moving the opto-boards out of the beam and passing the maximum allowable current (up to 20 mA per channel) through the arrays for several hours each day. The optical power increased during the annealing. However, there was insufficient time for a complete annealing. Consequently both the A.O.C. and ULM 5 Gb/s arrays had no optical power at  $\sim 50$  Mrad. The ULM 10 Gb/s arrays continued to have optical power of more than 100  $\mu W$  up to 65 Mrad and the Optowell arrays survived up to at least 70 Mrad. We believe that more arrays would have survived if we had more time for annealing.

The silicon PIN arrays survived the irradiation quite well. After the full SLHC dosage, the responsivities decreased to  $\sim$ 35% of the pre-irradiation level which is acceptable.

## 4. Novel optical package

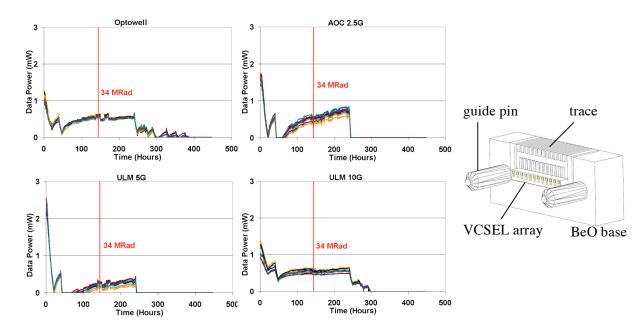
We have developed a new novel package for the VCSEL and PIN arrays. The package is as compact as the package provided by Academic Sinica, Taiwan for the current ATLAS pixel optical link. However, the base is fabricated using BeO instead of PCB for much better removal of the heat produced by the VCSEL which is the major heat source in the opto-link. The through hole vias for connecting to the anode and cathode pads on an array are replaced by three dimensional traces that go over the edge of the BeO base as shown in figure 4. Wire bonds connect the driver (receiver) chip to the VCSEL (PIN) array. This avoids the need for the challenging soldering of the micro-leads (250 µm width) to the BeO opto-board as it is difficult to supply sufficient heat to a tiny lead to attach to a trace on an excellent conductor. Moreover, the traces can be rewire-bonded for diagnostics and rerouting purposes as sometimes needed, especially during the R&D phase of a project.

The precise alignment of a VCSEL array to a MT ferrule is critical to achieve good optical power coupling; the alignment of a PIN array is much less critical because of the relatively large light sensitive area. Since the fibre ribbon is precisely placed with respect to the holes of the two guide pins in a MT ferrule, we align the VCSEL with respect to the guide pins. As a first step in the fabrication process, the guide pins are attached to the BeO base using epoxy with the precise relative location fixed by a MT ferrule. A VCSEL or PIN array is then aligned with respect to the guide pins under a microscope. We achieve good coupled optical power for the VCSEL arrays from various vendors. This demonstrates the principle of a compact opto-pack fabricated with BeO for heat management.

#### 5. Summary

We have studied the bandwidth of the electrical and optical transmission lines of the current optical link of the ATLAS pixel detector. The results indicate that the micro twisted-pair cables can transmit signals up to 1 Gb/s. The bandwidth of the fusion spliced fiber ribbon has been measured to be greater

than 2 Gb/s as reported in the previous conference [5]. The GaAs VCSEL arrays from three vendors have been found to have the radiation hardness suitable for the SLHC operation. The silicon PIN arrays by Truelight are also found to be radiation-hard. The current ATLAS pixel optical link architecture can therefore be used at the SLHC as a possible upgrade scenario. We have also demonstrated the feasibility of fabricating a novel opto-pack for housing VCSEL and PIN arrays with BeO as the substrate.



**Figure 3:** Optical power as a function of time (dosage) for the four VCSEL arrays that transmitted data to the control room. The power decreased during the irradiation but increased during the annealing as expected.

**Figure 4:** An optical package based on BeO.

#### 6. Acknowledgement

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## References

- [1] Arms K E et al. 2005 ATLAS Pixel Opto-Electronics Nucl. Instr. Meth. A 554 458
- [2] ATLAS Pixel Detector Technical Design Report, CERN/LHCC/98-13
- [3] See, for example, Schrader J H R et al. 2006 IEEE-J. Solid-State Circuits 41 990
- [4] MWS Wire Industries Twistite
- [5] Gan K K et al. 2007 Bandwidths of Micro Twisted-Pair Cables and Fusion Spliced SIMM-GRIN Fiber and Radiation Hardness of PIN/VCSEL Arrays *Proc. 12th Workshop on Electronics for LHC and Future Experiments* (Valencia, Spain, 2006) ed Letheren M and Claude S (CERN-2007-1) pp 223
- [6] Gregor I 2001 Optical Links for the ATLAS Pixel Detector *Ph.D. Thesis* University of Wuppertal
- [7] Van Ginneken A 1989 Nonionzing Energy Deposition in Silicon for Radiation Damage Studies *FERMILAB-FN-0522, Oct. 1989*
- [8] Chilingarov A, Meyer J S and Sloan T 1997 Radiation Damage due to NIEL in GaAs Particle Detectors *Nucl. Instrum. Meth.* A **395** 35
- [9] The fluences include a 50% safety margin